

TLV3604、TLV3605、TLV3607 具有 LVDS 输出的 800ps 高速 RRI 比较器

1 特性

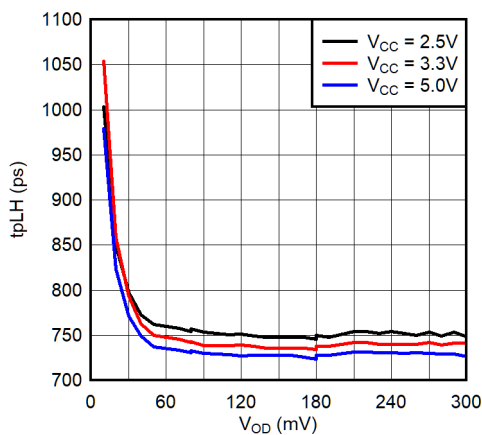
- 低传播延迟：800ps
- 低过驱动分散：350ps
- 静态电流：12.1mA
- 高切换频率：1.5GHz / 3.0Gbps
- 窄脉宽检测功能：600ps
- 数模转换器 (LVDS) 输出
- 电源电压范围：2.4V 至 5.5V
- 输入共模范围超出两个电源轨 200mV
- 低输入失调电压：±5mV
- 单通道和双通道选项

2 应用

- 激光雷达中的距离感测
- 飞行时间传感器
- 示波器和逻辑分析仪中的高速触发器功能
- 高速差分线路接收器
- 无人机视觉

3 说明

TLV3604、TLV3605 (单通道) 和 TLV3607 (双通道) 是具有 LVDS 输出和轨至轨输入的 800ps 高速比较器。这些比较器具有上述特性以及 2.4V 至 5.5V 的工作电压范围和 3Gbps 的高切换频率，因此非常适合激光雷达、时钟和数据恢复应用以及测试和测量系统。



TpLH v. 过驱动分散

同样，TLV3604、TLV3605 和 TLV3607 具有 350ps 的强大输入过驱动性能，并且能够检测仅 600ps 的窄脉冲宽度。由于输入过驱动而导致的传播延迟变化较小，与检测窄脉冲的能力相结合，不仅提高了系统性能，而且扩展了飞行时间 (ToF) 应用中的距离范围。

TLV3604、TLV3605 和 TLV3607 的低压差分信号 (LVDS) 输出还有助于提高数据吞吐量并优化功耗。互补输出通过抑制每个输出上的共模噪声来降低 EMI。LVDS 输出旨在驱动和直接连接可接受标准 LVDS 输入 (例如高速 FPGA 和 CPU) 的下游器件。

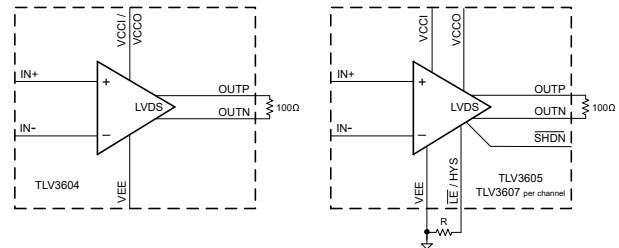
TLV3604 采用微型 6 引脚 SC-70 封装，因此更适用于空间敏感型应用，例如光学传感器模块。TLV3605 (单通道) 和 TLV3607 (双通道) 保持与 TLV3604 相同的性能，并在 12 引脚 QFN 和 16 引脚 WQFN 封装中提供可调节的迟滞控制、关断和锁存特性，因而成为测试和测量应用的理想选择。

器件信息

器件型号	封装 (1)	本体尺寸 (标称值) (2)
TLV3604	SC70 (6)	1.25mm × 2.00mm
TLV3605	QFN (12)	3.00mm × 3.00mm
TLV3607	WQFN (16)	4.00mm × 4.00mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

(2) 封装尺寸 (长 × 宽) 为标称值，并包括引脚 (如适用)。



功能方框图

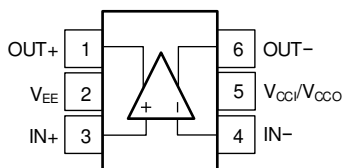


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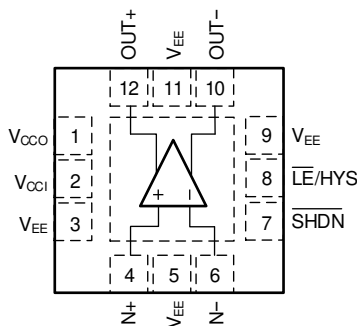
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4 Pin Configuration and Functions

Pin Configurations: TLV3604 and TLV3605



**图 4-1. DCK Package
6-Pin SC70
Top View**



**图 4-2. RVK Package
12-Pin QFN
Top View**

表 4-1. Pin Functions: TLV3604 and TLV3605

PIN			I/O	DESCRIPTION
NAME	TLV3604	TLV3605		
IN+	3	4	I	Non-inverting input
IN -	4	6	I	Inverting input
OUT+	1	12	O	Non-inverting output
OUT -	6	10	O	Inverting output
V _{EE}	2	3, 5, 9, 11	I	Negative power supply
V _{CCI}	5	2	I	Positive input section power supply
V _{CCO}	5	1	I	Positive output section power supply
SHDN	-	7	I	Shutdown control, active low
L _E /HYS	-	8	I	Adjustable hysteresis control and latch

4.1 Pin Configuration: TLV3607

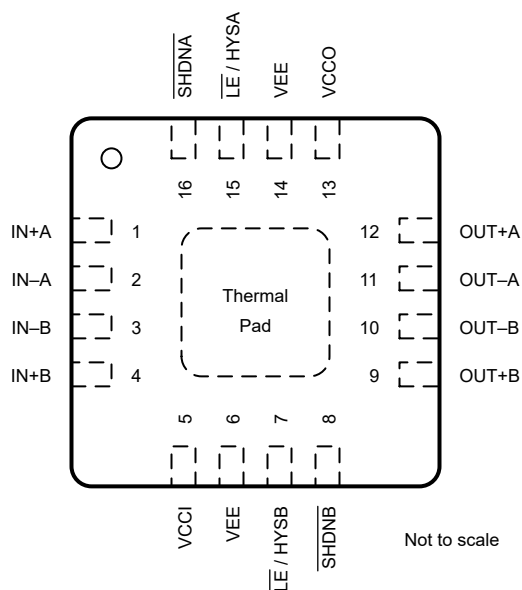


图 4-3. RTE Package
16-Pin WQFN with Exposed Thermal Pad
Top View

表 4-2. Pin Functions: TLV3607

PIN		I/O	DESCRIPTION
NAME	TLV3607		
IN+A	1	I	Channel A non-inverting input
IN – A	2	I	Channel A inverting input
IN – B	3	I	Channel B inverting input
IN+B	4	I	Channel B non-inverting input
OUT+A	12	O	Channel A non-inverting output
OUT – A	11	O	Channel A inverting output
OUT – B	10	O	Channel B inverting output
OUT+B	9	O	Channel B non-inverting output
V _{EE}	6, 14	I	Negative power supply
V _{CCI}	5	I	Positive input section power supply
V _{CCO}	13	I	Positive output section power supply
SHDNA	16	I	Channel A shutdown control (active low)
SHDNB	8	I	Channel B shutdown control (active low)
LE/HYSA	15	I	Channel A latch enable (active low) and adjustable hysteresis control
LE/HYSB	7	I	Channel B latch enable (active low) and adjustable hysteresis control

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	MIN	MAX	UNIT
Input Supply Voltage: $V_{CCI} - V_{EE}$	- 0.3	6	V
Output Supply Voltage: $V_{CCO} - V_{EE}$	- 0.3	6	V
Supply Voltage Difference: $V_{CCI} - V_{CCO}$	- 6	6	V
Input Voltage (IN+, IN -) ⁽²⁾	$V_{EE} - 0.3$	$V_{CCI} + 0.3$	V
Differential Input Voltage ($V_{DI} = IN+, IN -$)	$-(V_{CCI} + 0.3)$	$+(V_{CCI} + 0.3)$	V
Output Voltage (OUT+, OUT -) ⁽³⁾	$V_{EE} - 0.3$	$V_{CCO} + 0.3$	V
Shutdown Enable (SHDN)	$V_{EE} - 0.3$	$V_{CCO} + 0.3$	V
Latch and Hysteresis Control ($\overline{LE}/HYS$)	$V_{EE} - 0.3$	$V_{CCO} + 0.3$	V
Current into Input pins (IN+, IN - , $\overline{SHDN}$, $\overline{LE}/HYS$) ⁽²⁾	- 10	+10	mA
Current into Output pins (OUT+, OUT -) ⁽³⁾	- 10	+10	mA
Junction temperature, T_J		150	°C
Storage temperature, T_{stg}	- 65	150	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.3V beyond the supply rails or 6V, whichever is lower, must be current-limited to 10mA or less.
- (3) Output terminals are diode-clamped to the power-supply rails. Output signals that can swing more than 0.3V beyond the supply rails must be current-limited to 10mA or less.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	TLV3604 Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±1500	V
		TLV3605, TLV3607 Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Input Supply Voltage: $V_{CCI} - V_{EE}$	2.4	5.5	V
Output Supply Voltage: $V_{CCO} - V_{EE}$	2.4	5.5	V
Input Voltage Range (IN+, IN -)	$V_{EE} - 0.3$	$V_{CCI} + 0.3$	V
Shutdown Enable (SHDN)	$V_{EE} - 0.3$	$V_{CCO} + 0.3$	V
Latch and Hysteresis Control ($\overline{LE}/HYS$)	$V_{EE} - 0.3$	$V_{CCO} + 0.3$	V
Ambient temperature, T_A	- 40	125	°C

5.4 Thermal Information

THERMAL METRIC		TLV3604	TLV3605	TLV3607	UNIT
		DCK (SC70)	RVK (WQFN)	RTE (WQFN)	
		6 PINS	12 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	170.3	85.8	72.1	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	134.5	71.6	53.8	°C/W
$R_{\theta JC(bottom)}$	Junction-to-case (bottom) thermal resistance	N/A	15.1	35.7	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	63.3	52.7	45.9	°C/W
ψ_{JT}	Junction-to-top characterization parameter	43.7	4.1	2.1	°C/W
ψ_{JB}	Junction-to-board characterization parameter	63.1	52.7	45.9	°C/W

5.5 Electrical Characteristics ($V_{CCI} = V_{CCO} = 2.5V$ to $5V$)

$V_{CCI} = V_{CCO} = 2.5$ to $5V$, $V_{EE} = 0V$, $V_{CM} = V_{EE} + 300mV$, $R_{LOAD} = 100\Omega$, $C_L = 1pF$ probe capacitance, typical at $T_A = 25^\circ C$ (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
DC Input Characteristics						
V_{IO} ⁽¹⁾	Input offset voltage	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$	-5	± 0.5	5	mV
V_{CM}	Input common mode voltage range	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$	$V_{EE} - 0.2$		$V_{CCI} + 0.2$	V
V_{HYST}	Input hysteresis voltage			0		mV
C_{IN}	Input capacitance			1		pF
R_{DM}	Input differential mode resistance			67		k Ω
R_{CM}	Input common mode resistance			5		M Ω
I_B	Input bias current	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$	-5	-1	5	μA
I_{OS}	Input offset current	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$	-1		1	μA
CMRR ⁽¹⁾	Common-mode rejection ratio	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $V_{CM} = V_{EE} - 0.2V$ to $V_{CCI} + 0.2V$, $T_A = -40^\circ C$ to $+125^\circ C$	50	80		dB
PSRR ⁽¹⁾	Power-supply rejection ratio	$V_{CCI} = V_{CCO} = 2.5V$ to $5V$, $T_A = -40^\circ C$ to $+125^\circ C$	55	80		dB
DC Output Characteristics						
V_{OCM}	Output common mode voltage	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$	1.125	1.2	1.375	V
ΔV_{OCM}	Output common mode voltage mismatch	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$			50	mV
V_{OCM_PP}	Peak-to-Peak output common mode voltage			20		mVpp
V_{OD}	Differential output voltage	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$	250	350	450	mV
ΔV_{OD}	Differential output voltage mismatch	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$			10	mV
Power Supply						
I_{CC} (TLV3604)	Total quiescent current	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$		12.1	16.5	mA
I_{CCI} (TLV3605)	Input stage quiescent current	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$		7.5	10.5	mA
I_{CCO} (TLV3605)	Output stage quiescent current	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$		5.2	7.0	mA
I_{CCI} (TLV3607)	Input stage quiescent current per channel	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$		7.5	10.5	mA
I_{CCO} (TLV3607)	Output stage quiescent current per channel	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$		5.2	7.0	mA
AC Characteristics						
t_{PD}	Propagation delay	$V_{OVERDRIVE} = V_{UNDERDRIVE} = 50mV$, 50MHz Squarewave		800		ps
t_{PD_SKEW}	Propagation delay skew	$V_{OVERDRIVE} = V_{UNDERDRIVE} = 50mV$, 50MHz Squarewave		40		ps
Δt_{PD} (TLV3607 only)	Channel-to-channel propagation delay skew ⁽²⁾	$V_{OVERDRIVE} = V_{UNDERDRIVE} = 50mV$, 50MHz Squarewave		10		ps
$t_{CM_DISPERSION}$	Common dispersion	V_{CM} varied from V_{EE} to V_{CCI}		200		ps
$t_{OD_DISPERSION}$	Overdrive dispersion	Overdrive varied from 10mV to 250mV		350		ps
$t_{UD_DISPERSION}$	Underdrive dispersion	Underdrive varied from 10mV to 250mV		200		ps
t_R	Rise time	20% to 80%		350		ps
t_F	Fall time	80% to 20%		350		ps

5.5 Electrical Characteristics ($V_{CCI} = V_{CCO} = 2.5V$ to $5V$) (续)

$V_{CCI} = V_{CCO} = 2.5$ to $5V$, $V_{EE} = 0V$, $V_{CM} = V_{EE} + 300mV$, $R_{LOAD} = 100\Omega$, $C_L = 1pF$ probe capacitance, typical at $T_A = 25^\circ C$ (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f_{TOGGLE}	Input toggle frequency		1.5		GHz
TR	Toggle rate		3.0		Gbps
f_{TOGGLE} (TLV3607 only)	Input toggle frequency		1.3		GHz
TR (TLV3607 only)	Toggle rate		2.6		Gbps
PulseWidth	Minimum allowed input pulse width	$V_{OVERDRIVE} = V_{UNDERDRIVE} = 50mV$ $PW_{OUT} = 90\%$ of PW_{IN}	600		ps

Latching/Adjustable Hysteresis (TLV3605 and TLV3607)

V_{HYST}	Input hysteresis voltage	$R_{HYST} = \text{Floating}$	0		mV
V_{HYST}	Input hysteresis voltage	$R_{HYST} = 150k\Omega$	30		mV
V_{HYST}	Input hysteresis voltage	$R_{HYST} = 56k\Omega$	60		mV
V_{IH_LE}	$\overline{LE}$ pin input high level	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$	1.5		V
V_{IL_LE}	$\overline{LE}$ pin input low level	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$		0.35	V
I_{IH_LE}	$\overline{LE}$ pin input leakage current	$V_{LE} = V_{CCO}$ $T_A = -40^\circ C$ to $+125^\circ C$		3.5	μA
I_{IL_LE}	$\overline{LE}$ pin input leakage current	$V_{LE} = V_{EE}$ $T_A = -40^\circ C$ to $+125^\circ C$		40	μA
t_{SETUP}	Latch setup time		-3		ns
t_{HOLD}	Latch hold time		6		ns
t_{PL}	Latch to Q and $\overline{Q}$ delay		4		ns

Shutdown Characteristics (TLV3605 and TLV3607)

V_{IH_SD}	$\overline{SHDN}$ pin input high level	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$	1.5		V
V_{IL_SD}	$\overline{SHDN}$ pin input low level	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$		0.4	V
I_{IH_SD}	$\overline{SHDN}$ pin input leakage current	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $V_{SD} = V_{CCO}$, $T_A = -40^\circ C$ to $+125^\circ C$		2	μA
I_{IL_SD}	$\overline{SHDN}$ pin input leakage current	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $V_{SD} = V_{EE}$, $T_A = -40^\circ C$ to $+125^\circ C$		30	μA
I_{CCI_SD}	Input stage quiescent current per channel in Shutdown mode	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $V_{LE} = V_{CCO}$ $T_A = -40^\circ C$ to $+125^\circ C$		1.5	mA
I_{CCO_SD}	Output stage quiescent current per channel in Shutdown mode	$V_{CCI} = V_{CCO} = 2.5V$ and $5V$ $T_A = -40^\circ C$ to $+125^\circ C$		100	μA
t_{SLEEP}	Sleep time from Active to Shutdown mode	10% output swing	8		ns
t_{WAKEUP}	Wake up time from Shutdown mode	$V_{OD} = 50mV$, output valid	100		ns

- For TLV3605 and TLV3607, the V_{IO} is tested with $R_{HYST} = 150k\Omega$
- Differential propagation delay is defined as the larger of the two:
 $\Delta t_{PDLH} = t_{PDLH}(MAX) - t_{PDLH}(MIN)$
 $\Delta t_{PDHL} = t_{PDHL}(MAX) - t_{PDHL}(MIN)$
 where (MAX) and (MIN) denote the maximum and minimum values of a given measurement across the different comparator channels.

5.6 Typical Characteristics

At $T_A = 25^\circ\text{C}$, $V_{CC1}/V_{CCO} = 2.5\text{V}$ to 5.0V , $V_{CM} = 0.3\text{V}$, and input overdrive/underdrive = 50mV unless otherwise noted.

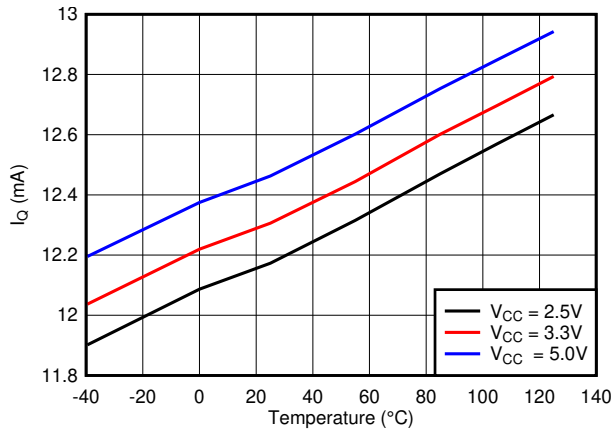


图 5-1. I_Q vs Temperature

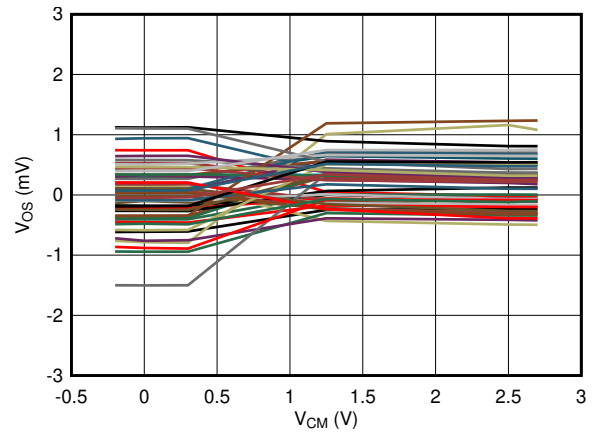


图 5-2. V_{OS} vs V_{CM} @ $V_{CC} = 2.5\text{V}$ - 50 Devices

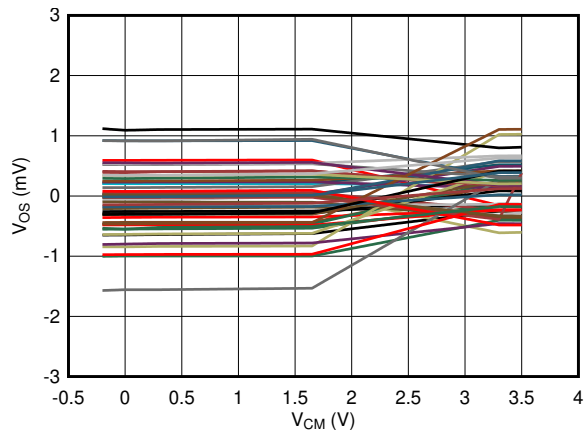


图 5-3. V_{OS} vs V_{CM} @ $V_{CC} = 3.3\text{V}$ - 50 Devices

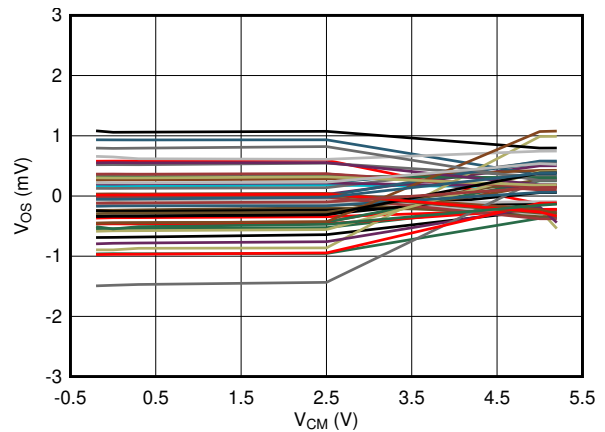


图 5-4. V_{OS} vs V_{CM} @ $V_{CC} = 5.0\text{V}$ - 50 Devices

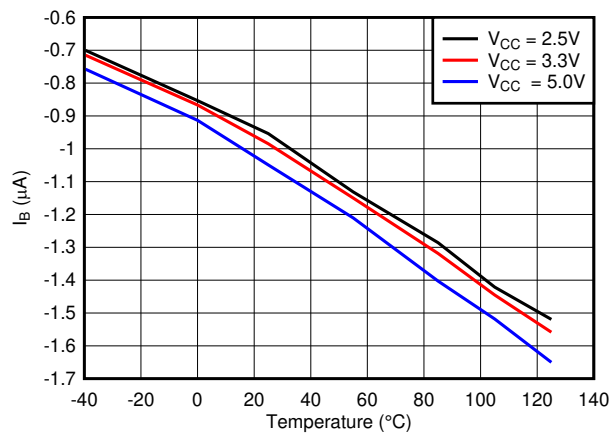


图 5-5. Bias Current vs Temperature

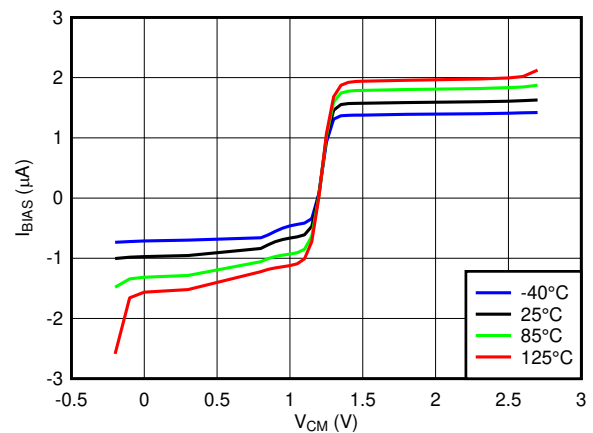


图 5-6. Input Bias Current vs V_{CM} @ $V_{CC} = 2.5\text{V}$

5.6 Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{CCI}/V_{CCO} = 2.5\text{V}$ to 5.0V , $V_{CM} = 0.3\text{V}$, and input overdrive/underdrive = 50mV unless otherwise noted.

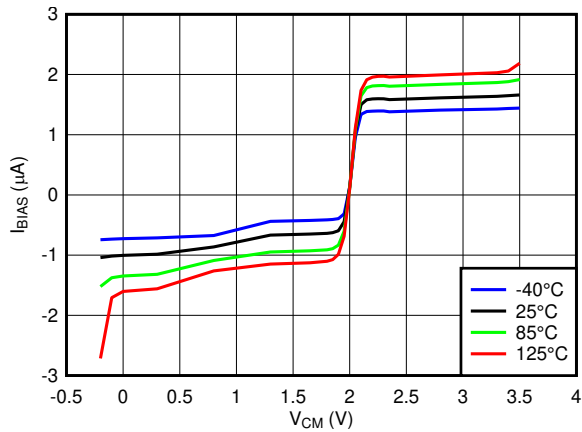


图 5-7. Input Bias Current vs V_{CM} @ $V_{CC} = 3.3\text{V}$

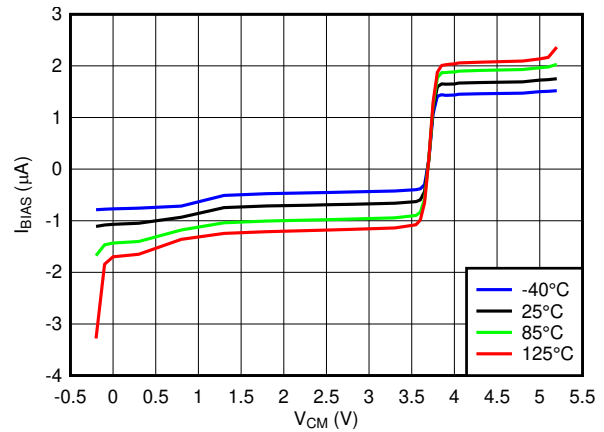


图 5-8. Input Bias Current vs V_{CM} @ $V_{CC} = 5.0\text{V}$

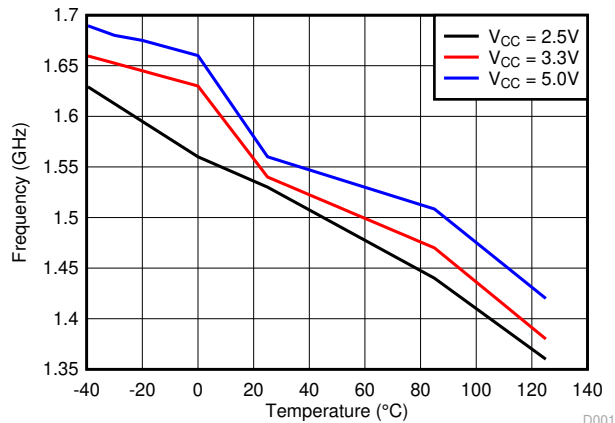


图 5-9. FToggle vs Temperature

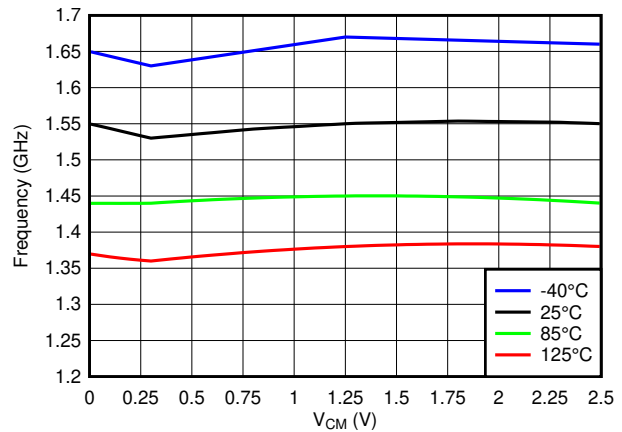


图 5-10. FToggle vs V_{CM} @ $V_{CC} = 2.5\text{V}$

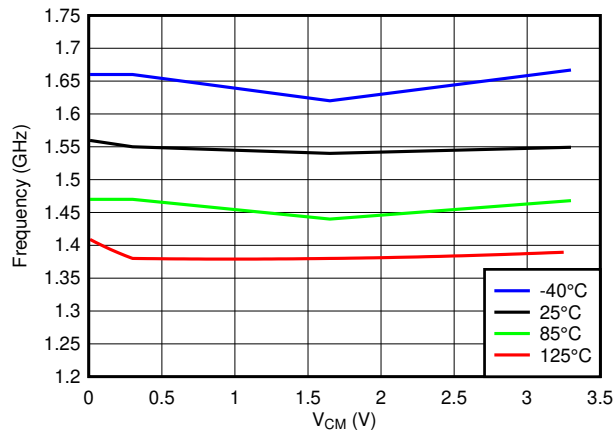


图 5-11. FToggle vs V_{CM} @ $V_{CC} = 3.3\text{V}$

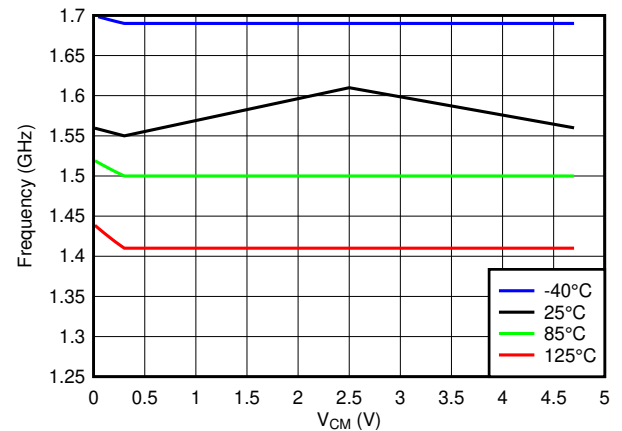


图 5-12. FToggle vs V_{CM} @ $V_{CC} = 5.0\text{V}$

5.6 Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{CC1}/V_{CC0} = 2.5\text{V}$ to 5.0V , $V_{CM} = 0.3\text{V}$, and input overdrive/underdrive = 50mV unless otherwise noted.

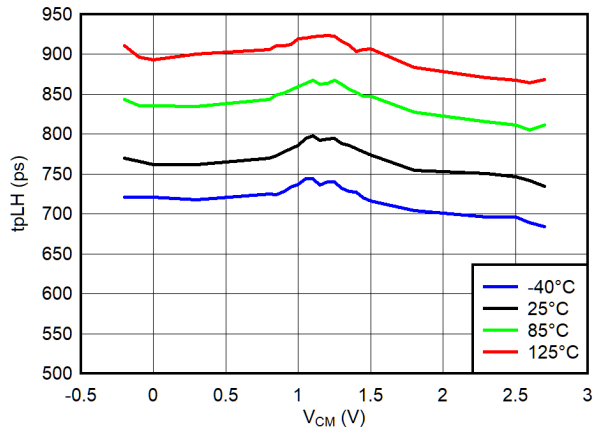


图 5-13. T_{PLH} vs V_{CM} @ $V_{CC} = 2.5\text{V}$

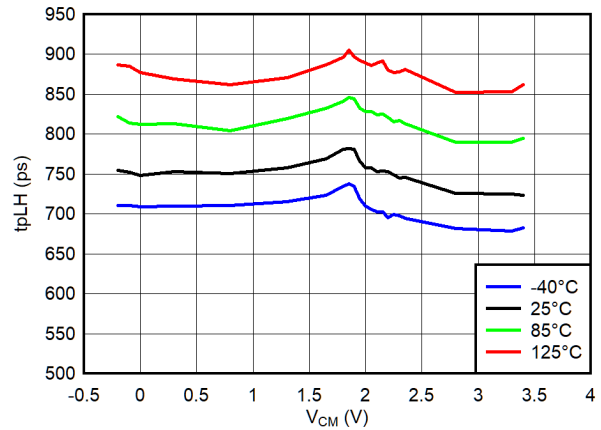


图 5-14. T_{PLH} vs V_{CM} @ $V_{CC} = 3.3\text{V}$

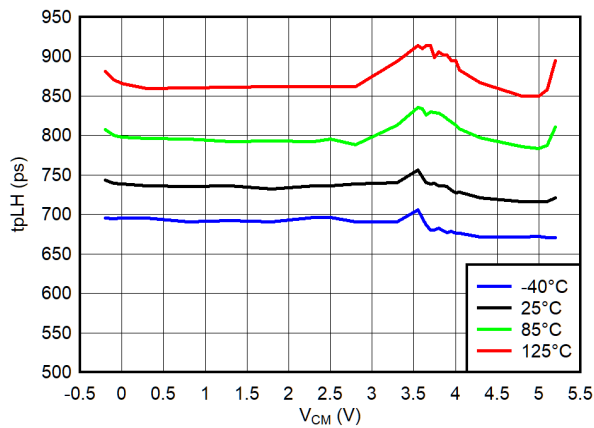


图 5-15. T_{PLH} vs V_{CM} @ $V_{CC} = 5.0\text{V}$

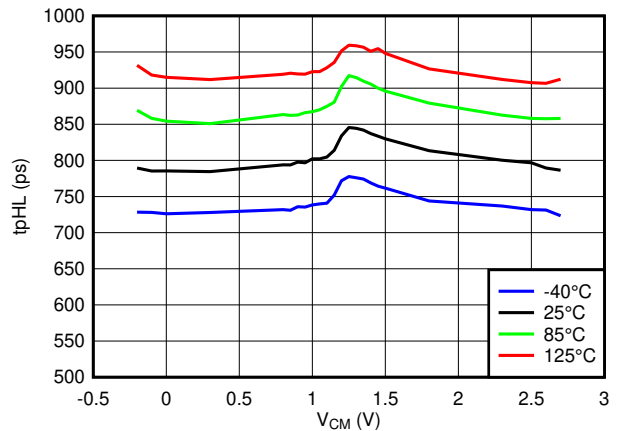


图 5-16. T_{PHL} vs V_{CM} @ $V_{CC} = 2.5\text{V}$

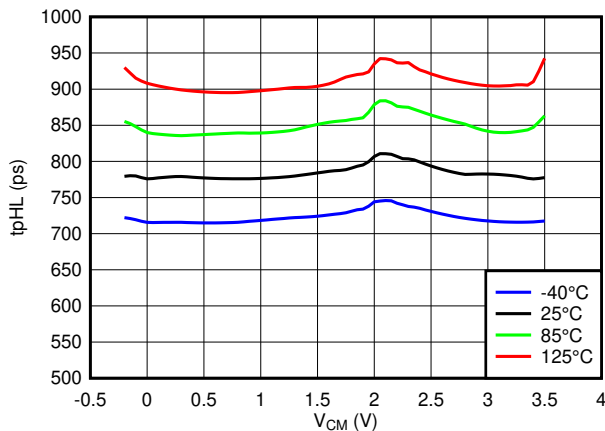


图 5-17. T_{PHL} vs V_{CM} @ $V_{CC} = 3.3\text{V}$

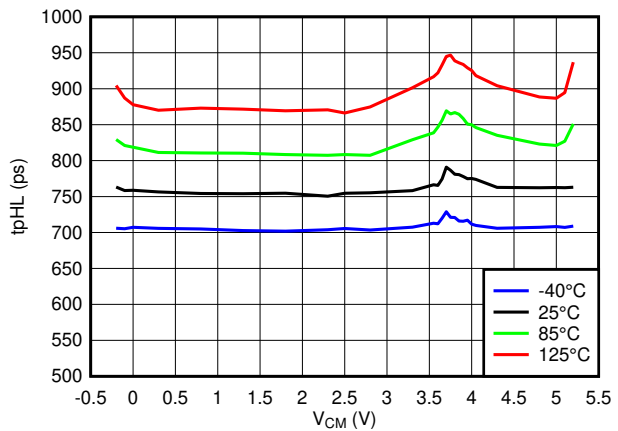


图 5-18. T_{PHL} vs V_{CM} @ $V_{CC} = 5.0\text{V}$

5.6 Typical Characteristics (continued)

At $T_A = 25^\circ\text{C}$, $V_{CCI}/V_{CCO} = 2.5\text{V to } 5.0\text{V}$, $V_{CM} = 0.3\text{V}$, and input overdrive/underdrive = 50mV unless otherwise noted.

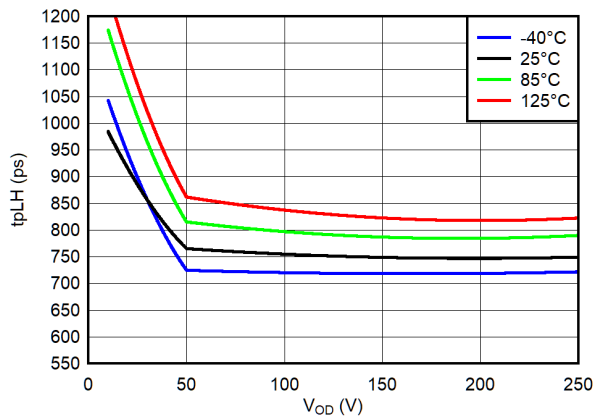


图 5-19. T_{PLH} vs Input Overdrive @ $V_{CC} = 2.5\text{V}$

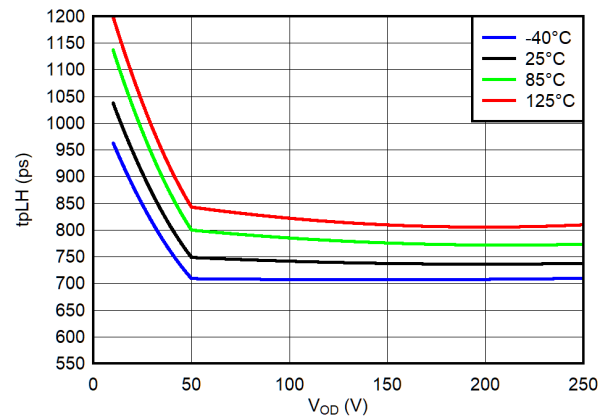


图 5-20. T_{PLH} vs Input Overdrive @ $V_{CC} = 3.3\text{V}$

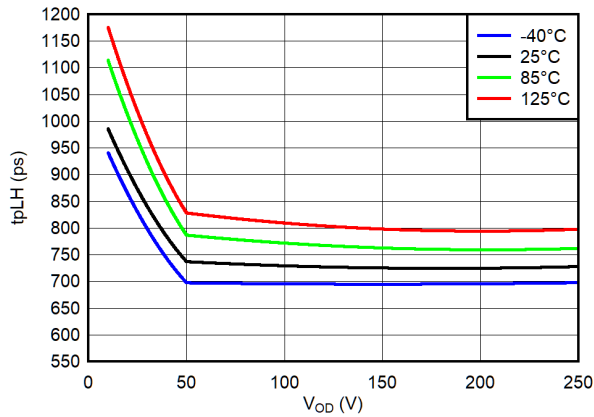


图 5-21. T_{PLH} vs Input Overdrive @ $V_{CC} = 5.0\text{V}$

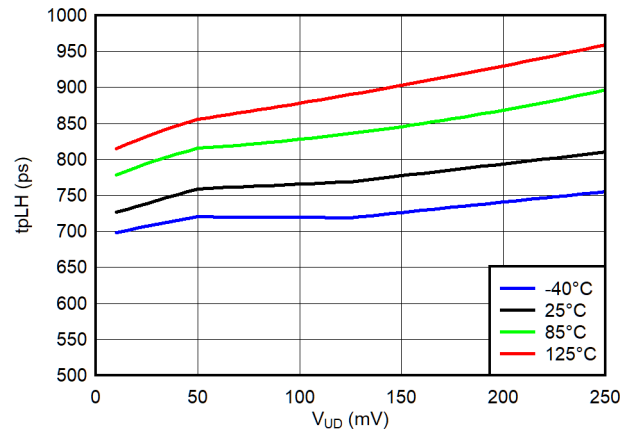


图 5-22. T_{PLH} vs Input Underdrive @ $V_{CC} = 2.5\text{V}$

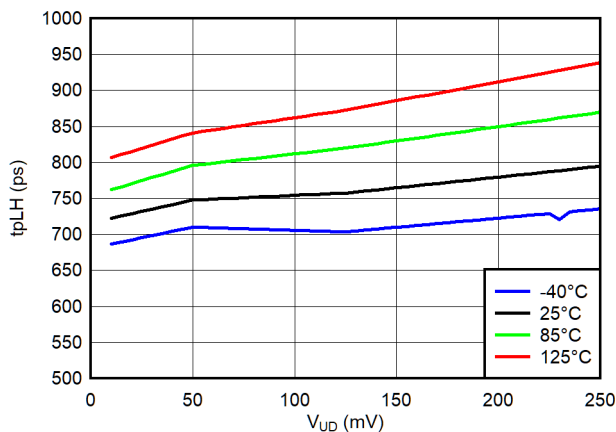


图 5-23. T_{PLH} vs Input Underdrive @ $V_{CC} = 3.3\text{V}$

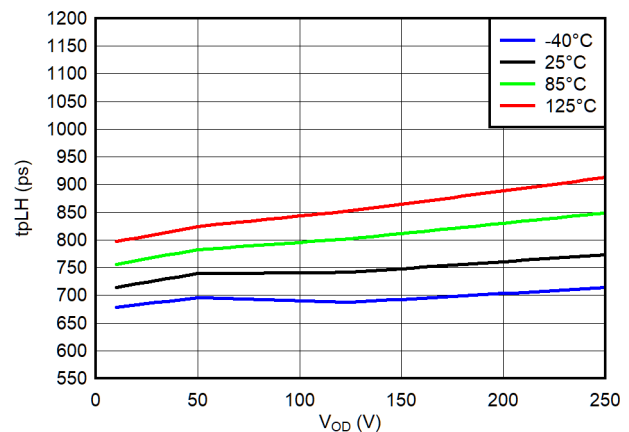


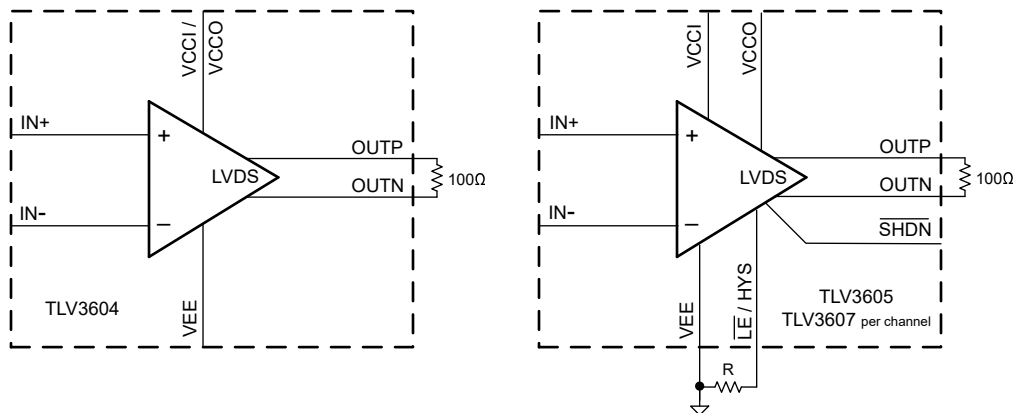
图 5-24. T_{PLH} vs Input Underdrive @ $V_{CC} = 5.0\text{V}$

6 Detailed Description

6.1 Overview

The TLV3604, TLV3605, and TLV3607 are 800ps, high-speed comparators with LVDS outputs and rail-to-rail inputs. These features, along with an operating voltage range of 2.4V to 5.5V and a high toggle frequency of 3Gbps, make the TLV3604, TLV3605, and TLV3607 well suited for LIDAR, clock and data recovery applications, and test and measurement systems.

6.2 Functional Block Diagram



6.3 Feature Description

The TLV3604 and TLV3605 (single channel) and TLV3607 (dual channel) are high-speed comparators with rail-to-rail inputs and LVDS outputs. The rail-to-rail input stage is capable of operating up to 200mV beyond each power supply rail with minimal input offset. The TLV3605 (single) and TLV3607 (dual) have similar performance as the TLV3604 while providing adjustable hysteresis, latching function, and shutdown mode.

6.4 Device Functional Modes

The TLV3604 has a single functional mode and is operational when the power supply voltage is greater than the minimum operating voltage. The TLV3605 and TLV3607 have an active and shutdown mode. The TLV3605 and TLV3607 are in shutdown mode when the SHDN pin is logic low. To allow for easy interface with 1.8V FPGAs and CPUs, the SHDN pin is 1.8V logic compliant and independent of the comparator power supply.

6.4.1 Rail-to-Rail Inputs

The TLV3604, TLV3605, and TLV3607 feature input stages capable of operating 200mV below or above the power supply rails, allowing for zero cross detection and maximizing input dynamic range. With low input offset voltage, the comparators improve system performance in high sensitivity signal detection.

6.4.2 LVDS Output

The TLV3604, TLV3605, and TLV3607 outputs are LVDS compliant. When the input of the downstream device is terminated with a 100 Ω resistor, it provides a ± 350 mV LVDS swing. Fully differential outputs enable fast digital toggling and reduce EMI compared to single-ended output standards.

7 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

7.1 Application Information

The TLV3604, TLV3605, and TLV3607 comparators feature rail-to-rail inputs and a LVDS output stage that is well-suited for high speed applications that require low power consumption. The 800ps propagation delay of the comparators improve performance and extend the range for applications involving optical reception, triggers for test and measurement systems, and transceivers that require a high speed signal to be carried over a certain distance.

7.1.1 Comparator Inputs

The TLV3604, TLV3605, and TLV3607 are rail-to-rail input comparators, with an input common-mode range that exceeds the supply rails by 200mV for both positive and negative supplies.

7.1.2 Capacitive Loads

Under reasonable capacitive loads, the device maintains specified propagation delay. However, excessive capacitive loading under high switching frequencies may increase supply current, propagation delay, or induce decreased slew rate.

7.1.3 Latch Functionality

The latch pin for the TLV3605 and TLV3607 holds the output state of the device when the voltage at the LEB/HYST pin is less than 800mV above V_{EE} . This is particularly useful when the output state is intended to remain unchanged. An important consideration of the latch functionality is the latch hold time. Latch hold time is the minimum time (after the latch pin is asserted) required for properly latching the comparator output.

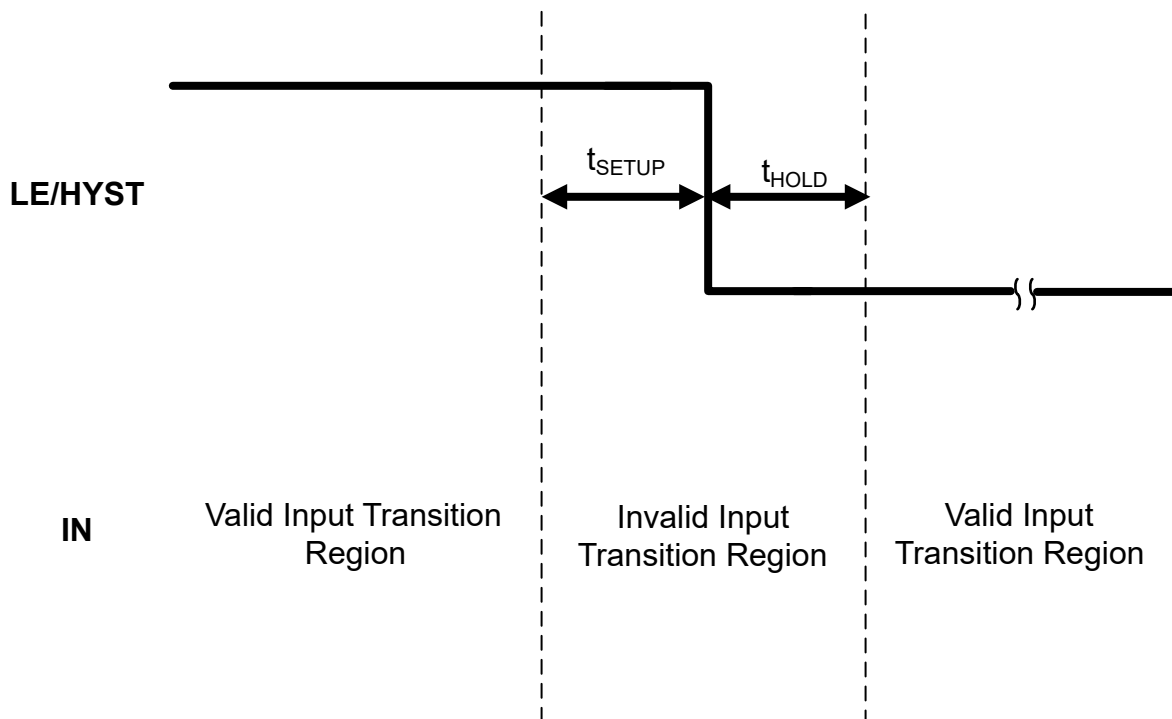


图 7-1. Valid Latch Diagram

Likewise, latch setup time is defined as the time that the input must be stable before the latch pin is asserted low. The figure above illustrates when the input can transition for a valid latch. Note that the typical setup time in the EC table is negative; this is due to the internal trace delays of the LEB/HYST pin relative to the input pin trace delays.

A small delay in the output response is shown below when the TLV3605 and TLV3607 exits a latched output stage.

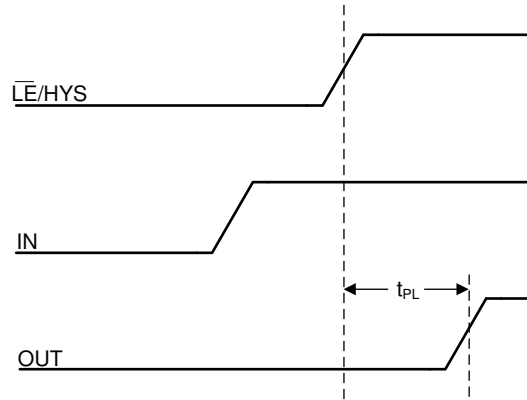


图 7-2. Latch Disable with Input Change

7.1.4 Adjustable Hysteresis

As a result of a comparator's high open loop gain, there is a small band of input differential voltage where the output can toggle back and forth between "logic high" and "logic low" states. This can cause design challenges for inputs with slow rise and fall times or systems with excessive noise.

These challenges can be overcome by adding hysteresis to the comparator. Since the TLV3604 does not have internal hysteresis, external hysteresis can be applied in the form of a positive feedback loop that adjusts the trip point of the comparator depending on its current output state. See the Typical Application section for more details.

The TLV3605 and TLV3607 have a LEB/HYST pin that can be used to increase the internal hysteresis of the comparator. To change the internal hysteresis of the TLV3605 and TLV3607, connect a single resistor as shown in the [adjusting hysteresis figure](#) between the LEB/HYST pin and VEE. A curve of hysteresis versus resistance is provided below to provide guidance in setting the desired amount of hysteresis.

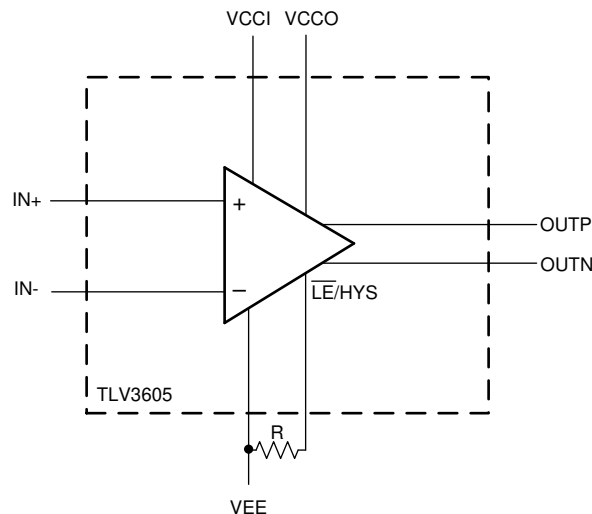
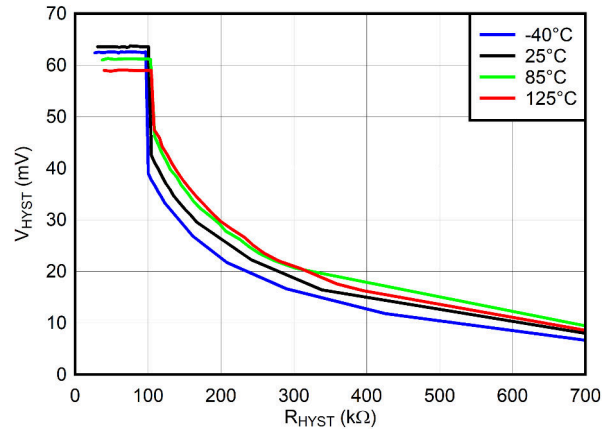


图 7-3. Adjusting Hysteresis with an External Resistor (R)

图 7-4. V_{HYST} (mV) vs R_{HYST} (kΩ), V_{CC} = 3.3V

7.2 Typical Application

7.2.1 Non-Inverting Comparator With Hysteresis

A way to implement external hysteresis is to add two resistors to the circuit: one in series between the reference voltage and the inverting pin, and another from the inverting pin to one of the differential output pins.

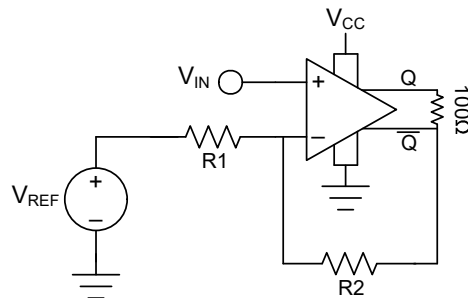


图 7-5. Non-Inverting Comparator with Hysteresis Circuit

7.2.1.1 Design Requirements

表 7-1. Design Parameters

PARAMETER	VALUE
V _{HYS}	50mV
V _{REF}	2.5V
V _{T1}	2.34V
V _{T2}	2.29V
Q	1.375V
Q̄	1.025V

7.2.1.2 Detailed Design Procedure

First, create an equation for V_T that covers both output voltages when the output is high or low.

$$V_{T1} = \frac{V_{REF}R_2 + QR_1}{R_1 + R_2} \quad (1)$$

$$V_{T2} = \frac{V_{REF}R_2 + \bar{Q}R_1}{R_1 + R_2} \quad (2)$$

The hysteresis voltage in this network is equal to the difference in the two threshold voltage equations.

$$V_{HYS} = V_{T1} - V_{T2} \quad (3)$$

$$V_{HYS} = \frac{V_{REF}R_2 + QR_1}{R_1 + R_2} - \frac{V_{REF}R_2 + \bar{Q}R_1}{R_1 + R_2} \quad (4)$$

$$V_{HYS} = \frac{(Q - \bar{Q})R_1}{R_1 + R_2} \quad (5)$$

$$V_{HYS} = \frac{V_{OD}R_1}{R_1 + R_2} \quad (6)$$

Note that these equations do not take into account the effects of the internal hysteresis and offset voltage of the comparator. Design parameters need to be adjusted accordingly.

Select a value for R2. Plug in given values for V_{REF} , V_{T1} , V_{T2} , Q, and $\bar{Q}$, and solve for R1. For the given example, $R_2 = 50k\ \Omega$, and R1 is solved as $= 8.3k\ \Omega$.

7.2.1.3 Application Performance Plots

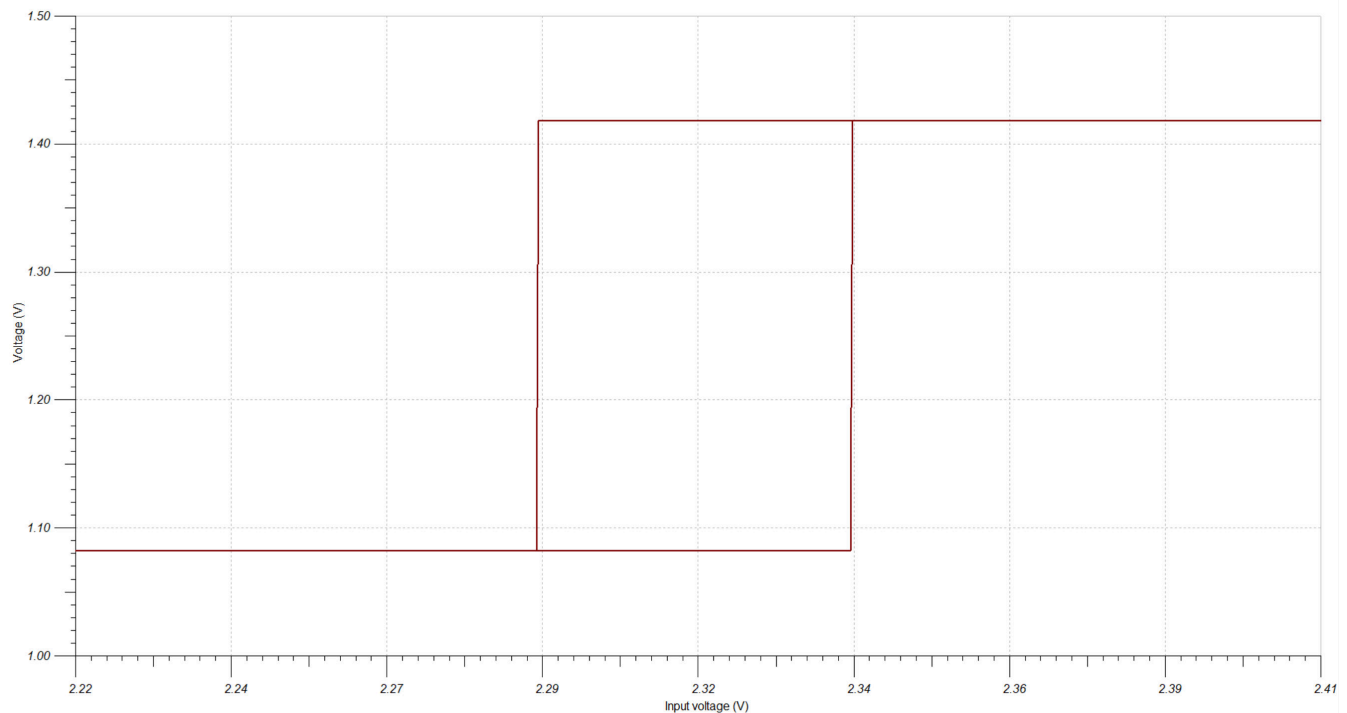


图 7-6. Hysteresis Curve for LVDS Comparator

7.2.2 Optical Receiver

The TLV3604, TLV3605, and TLV3607 can be used in conjunction with a high performance amplifier such as the OPA855 to create an optical receiver as shown in the 图 7-7. The photo diode is connected to a bias voltage and is being driven with a pulsed laser. The OPA855 takes the current conducting through the diode and translates it into a voltage for a high speed comparator to detect. The TLV3604, TLV3605, and TLV3607 will then output the proper LVDS signal according to the threshold set (V_{REF2}).

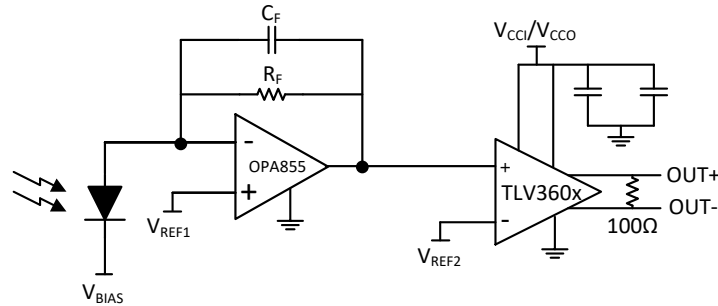


图 7-7. Optical Receiver

7.2.3 Logic Clock Source to LVDS Transceiver

The 图 7-8 shows a logic clock source being terminated and driven with the TLV3604, TLV3605, and TLV3607 across a CAT6 Cable to receive an equivalent LVDS clock signal at the receiver end.

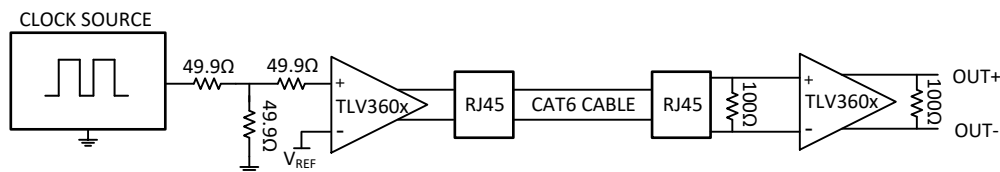


图 7-8. LVDS Clock Transceiver

7.2.4 External Trigger Function for Oscilloscopes

图 7-9 is a typical configuration for creating an external trigger on oscilloscopes. The user adjusts the trigger level, and a DAC converts this trigger level to a voltage the TLV360x can use as a reference. The input voltage from an oscilloscope channel is then compared to the trigger reference voltage, and the TLV3604, TLV3605, and TLV3607 sends an LVDS signal to a downstream FPGA to begin a capture.

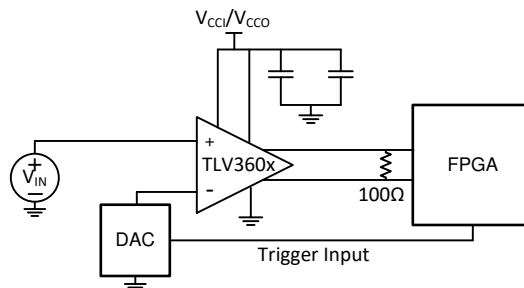


图 7-9. External Trigger Function

7.3 Power Supply Recommendations

The TLV3604, TLV3605, and TLV3607 are recommended for operation from 2.4V to 5.5V. One benefit of the TLV3605 and TLV3607 is that the comparator has separate input and output supply pins (VCCI and VCCO). This provides a system designer the flexibility of powering the input stage with a higher supply voltage such as 5V to maximize the dynamic range of the input while powering the output stage with a 2.5V supply to save power. Regardless of the VCCO supply voltage, the control pins such as LEB and SHDNB are 1.8V logic compliant.

7.4 Layout

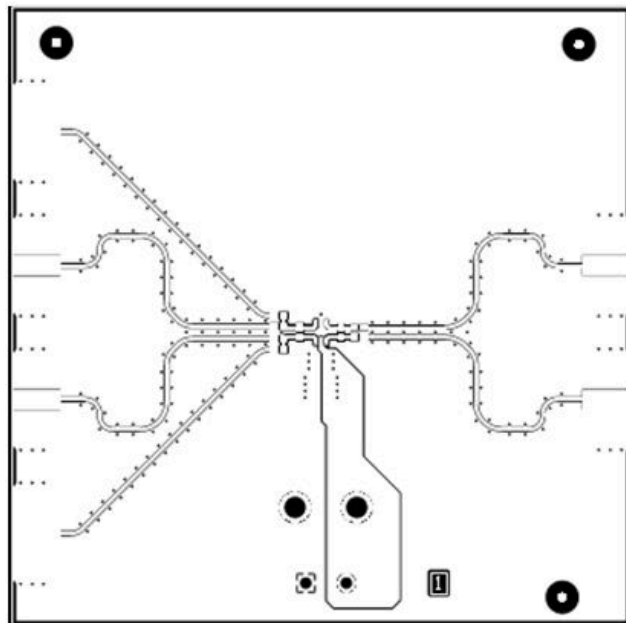
7.4.1 Layout Guidelines

Comparators are very sensitive to input noise. For best results, adhere to the following layout guidelines.

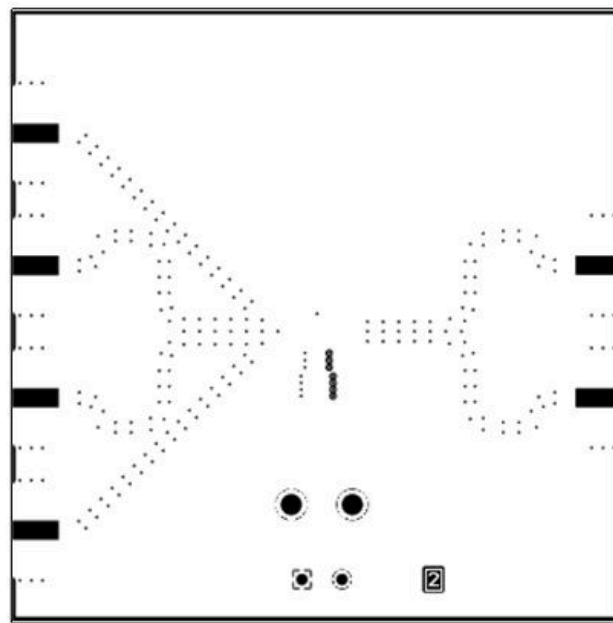
1. Use a printed-circuit-board (PCB) with a good, unbroken, low-inductance ground plane. Proper grounding (use of a ground plane) helps maintain specified device performance and input/output trace impedances.
2. To minimize supply noise, place a decoupling capacitor (0.1- μ F ceramic, surface-mount capacitor) directly between VCCI/VCCO and VEE.
3. On the inputs and outputs, utilize matched trace lengths to minimize timing skew. Also, minimize trace lengths and maximize ground pour spacings around the input and output traces to limit parasitic capacitance.
4. Solder the device directly to the PCB rather than using a socket.
5. For slow-moving input signals, take care to prevent parasitic feedback. A small capacitor (1000pF or less) placed between the inputs can help eliminate oscillations in the transition region. This capacitor causes minimal degradation to propagation delay when source impedance is low.
6. Use a 100 Ω termination resistor across the device's LVDS outputs.
7. Use higher performance substrate materials such as Rogers or High-Speed FR4.
8. PCB signal layers from the TLV3604EVM are shown for reference.

7.4.2 Layout Example

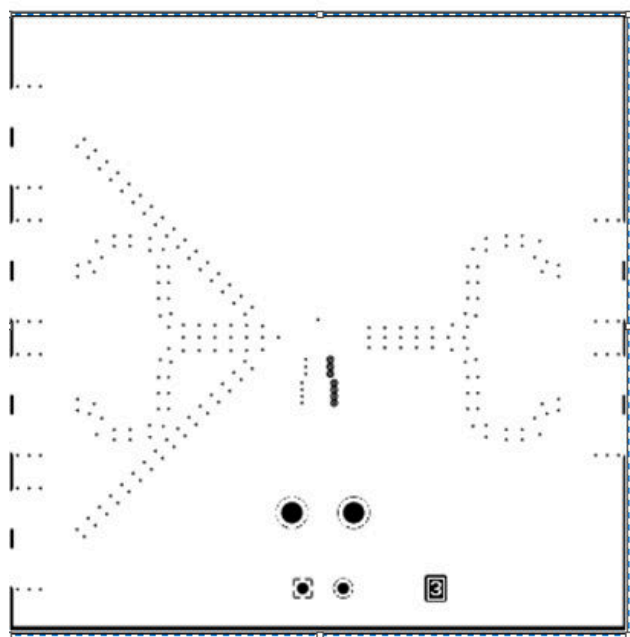
[Figure 10-1](#) shows the 4 layer PCB signal routing for the TLV3604EVM as an example for how layout on this device can be done.



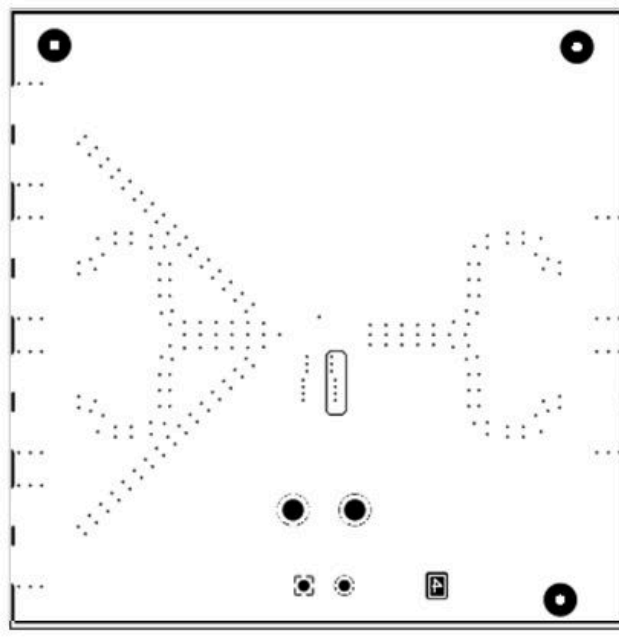
Top Layer



GND-1 Layer



GND-2 Layer



Bottom Layer

图 7-10. TLV3604EVM Layout Example

8 Device and Documentation Support

8.1 Device Support

8.1.1 Development Support

[LIDAR Pulsed Time of Flight Reference Design](#)

8.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [通知](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

8.3 支持资源

[TI E2E™ 中文支持论坛](#) 是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [使用条款](#)。

8.4 Trademarks

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8.5 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

8.6 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

9 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision E (July 2023) to Revision F (June 2024)	Page
• 将 TLV3607 传播延迟降低至 800ps.....	1
• Updated Typical Application section.....	16

Changes from Revision D (June 2021) to Revision E (July 2023)	Page
• 在整个数据表中添加了双通道 TLV3607.....	1

Changes from Revision C (April 2021) to Revision D (June 2021)	Page
• Update Hysteresis Curve.....	15

Changes from Revision B (December 2020) to Revision C (April 2021)	Page
• Updated Typical Performance Curves.....	9
• Updated Latch Functionality.....	14

Changes from Revision A (August 2020) to Revision B (December 2020)	Page
• APL 到 RTM 版本.....	1

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV3604DCKR	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1HF
TLV3604DCKR.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1HF
TLV3604DCKRG4.B	Active	Production	SC70 (DCK) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1HF
TLV3604DCKT	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1HF
TLV3604DCKT.B	Active	Production	SC70 (DCK) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1HF
TLV3605RVKR	Active	Production	WQFN (RVK) 12	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3605
TLV3605RVKR.B	Active	Production	WQFN (RVK) 12	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3605
TLV3605RVKT	Active	Production	WQFN (RVK) 12	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3605
TLV3605RVKT.B	Active	Production	WQFN (RVK) 12	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3605
TLV3607RTER	Active	Production	WQFN (RTE) 16	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL3607
TLV3607RTER.B	Active	Production	WQFN (RTE) 16	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL3607

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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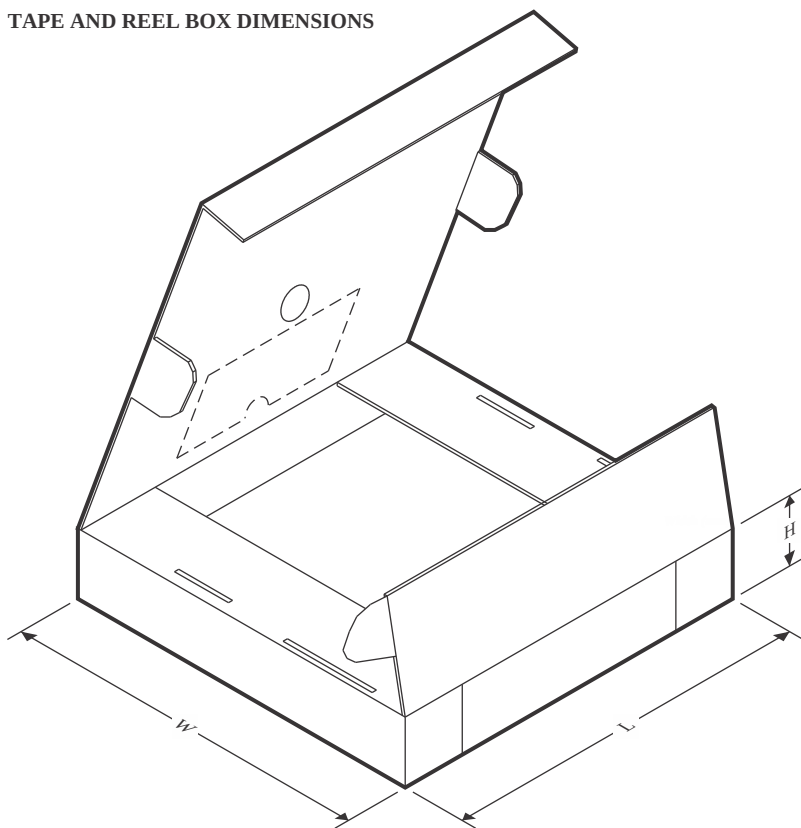
TAPE AND REEL INFORMATION



*All dimensions are nominal

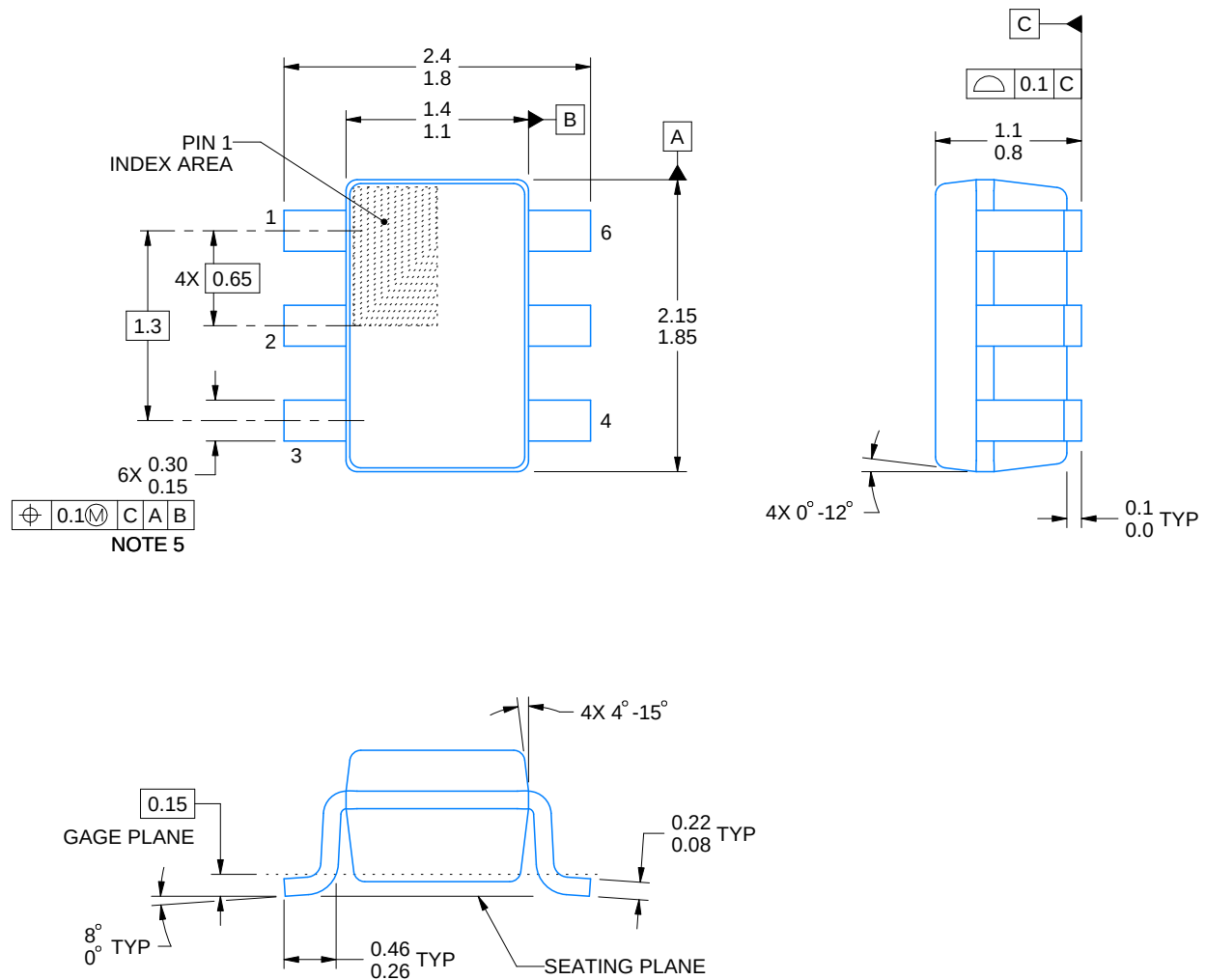
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV3604DCKR	SC70	DCK	6	3000	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
TLV3604DCKT	SC70	DCK	6	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
TLV3605RVKR	WQFN	RVK	12	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TLV3605RVKT	WQFN	RVK	12	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TLV3607RTER	WQFN	RTE	16	5000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

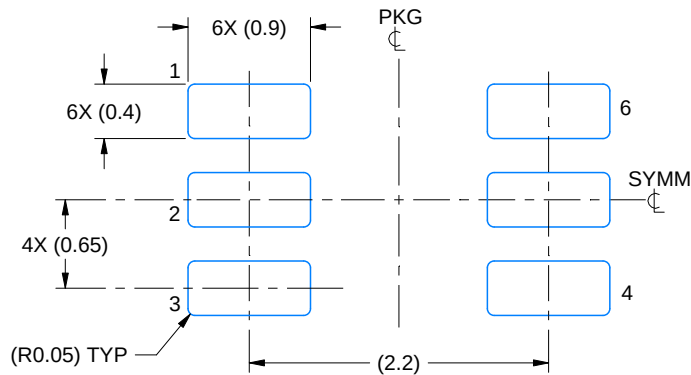
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV3604DCKR	SC70	DCK	6	3000	183.0	183.0	20.0
TLV3604DCKT	SC70	DCK	6	250	183.0	183.0	20.0
TLV3605RVKR	WQFN	RVK	12	3000	367.0	367.0	35.0
TLV3605RVKT	WQFN	RVK	12	250	210.0	185.0	35.0
TLV3607RTER	WQFN	RTE	16	5000	367.0	367.0	35.0



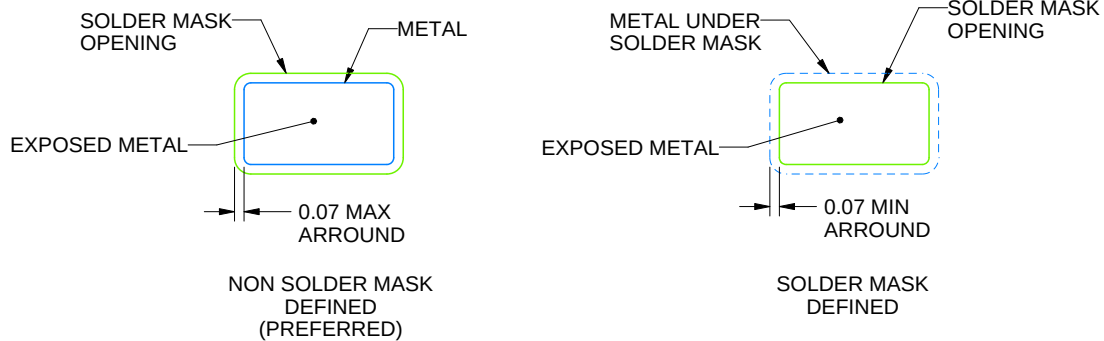
4214835/D 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
4. Falls within JEDEC MO-203 variation AB.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X

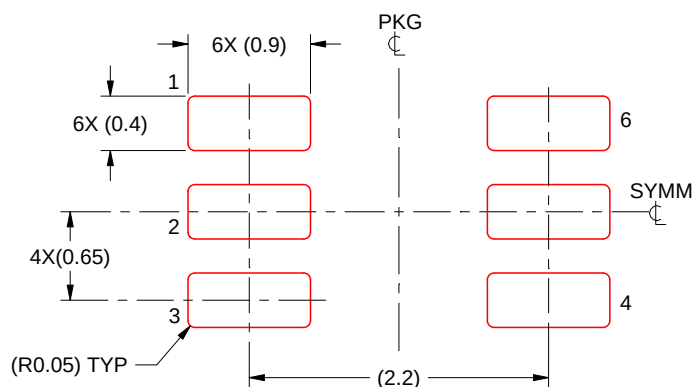


SOLDER MASK DETAILS

4214835/D 11/2024

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
 BASED ON 0.125 THICK STENCIL
 SCALE:18X

4214835/D 11/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

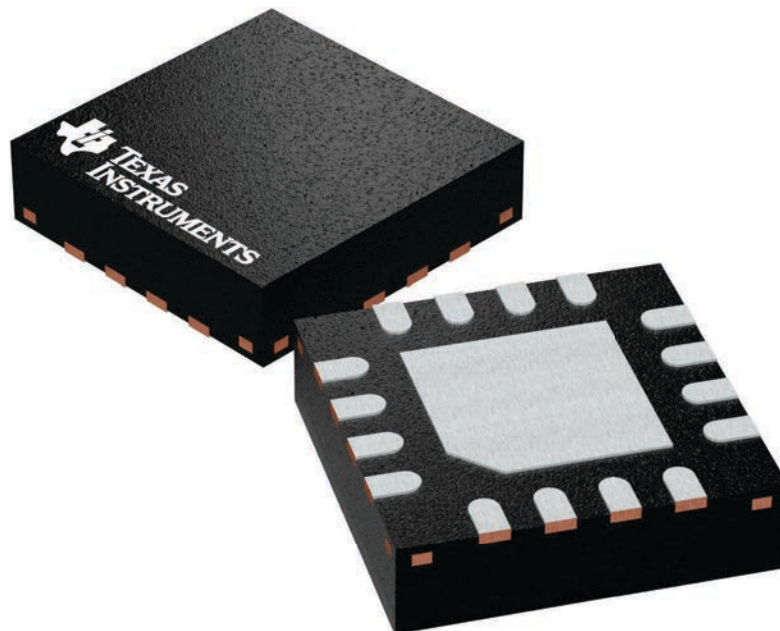
RTE 16

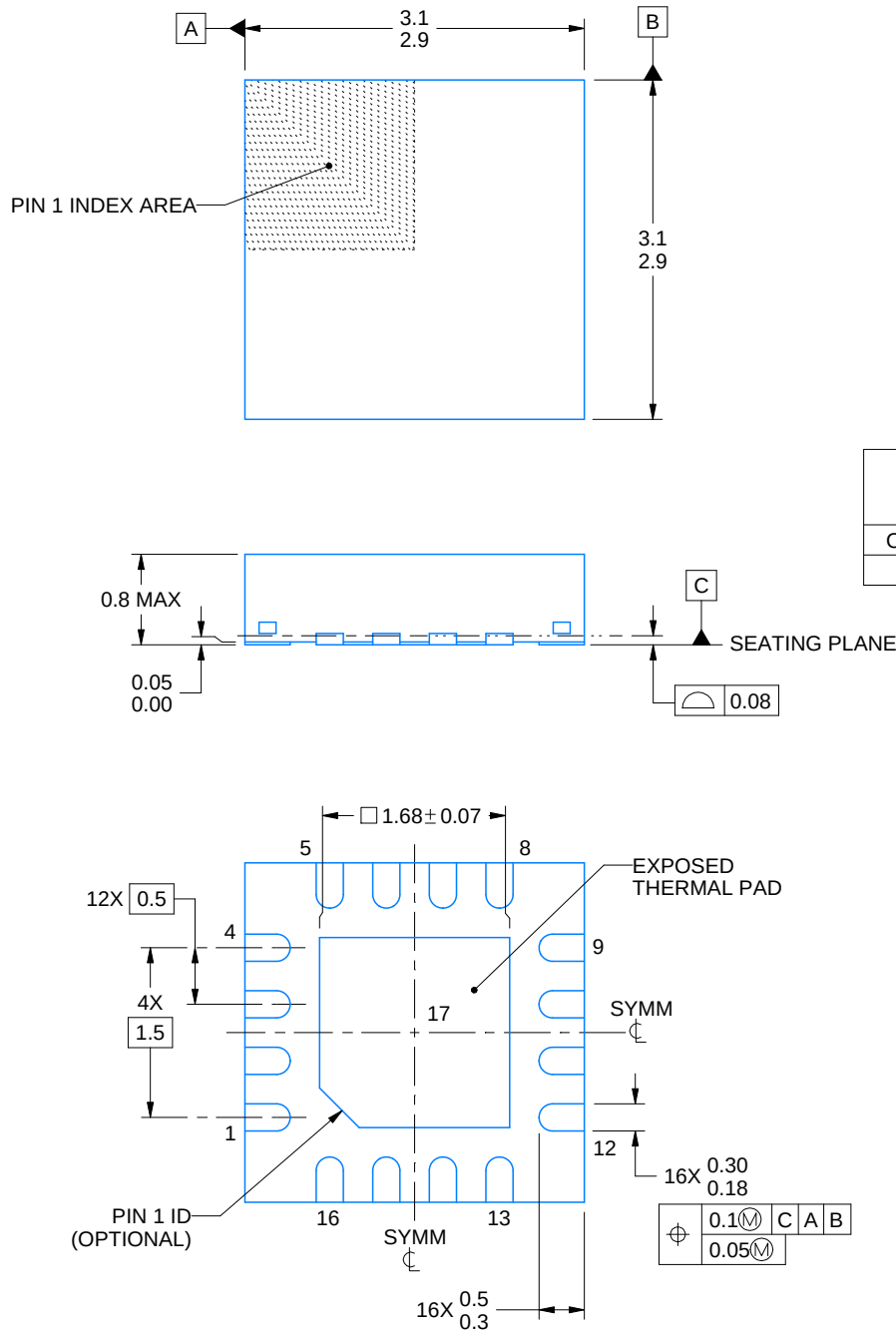
WQFN - 0.8 mm max height

3 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.





4219117/B 04/2022

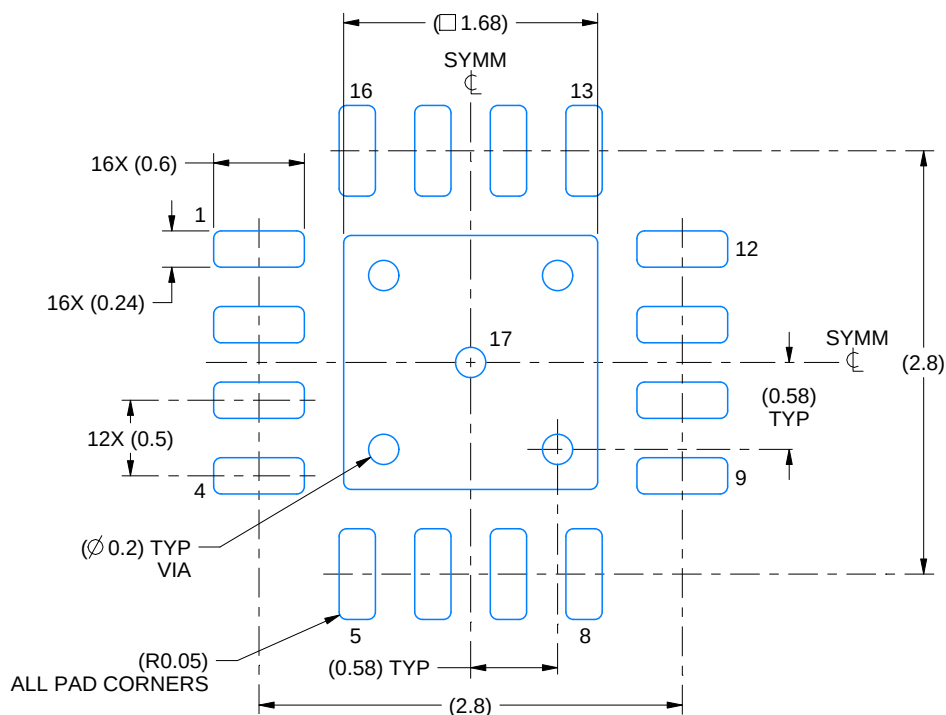
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

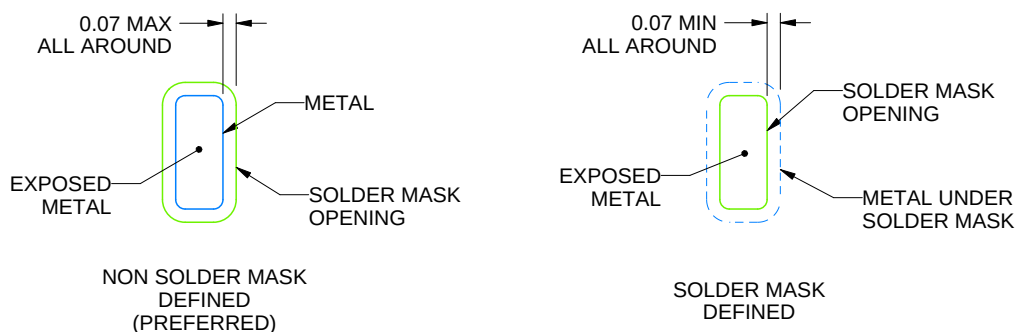
RTE0016C

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:20X



SOLDER MASK DETAILS

4219117/B 04/2022

NOTES: (continued)

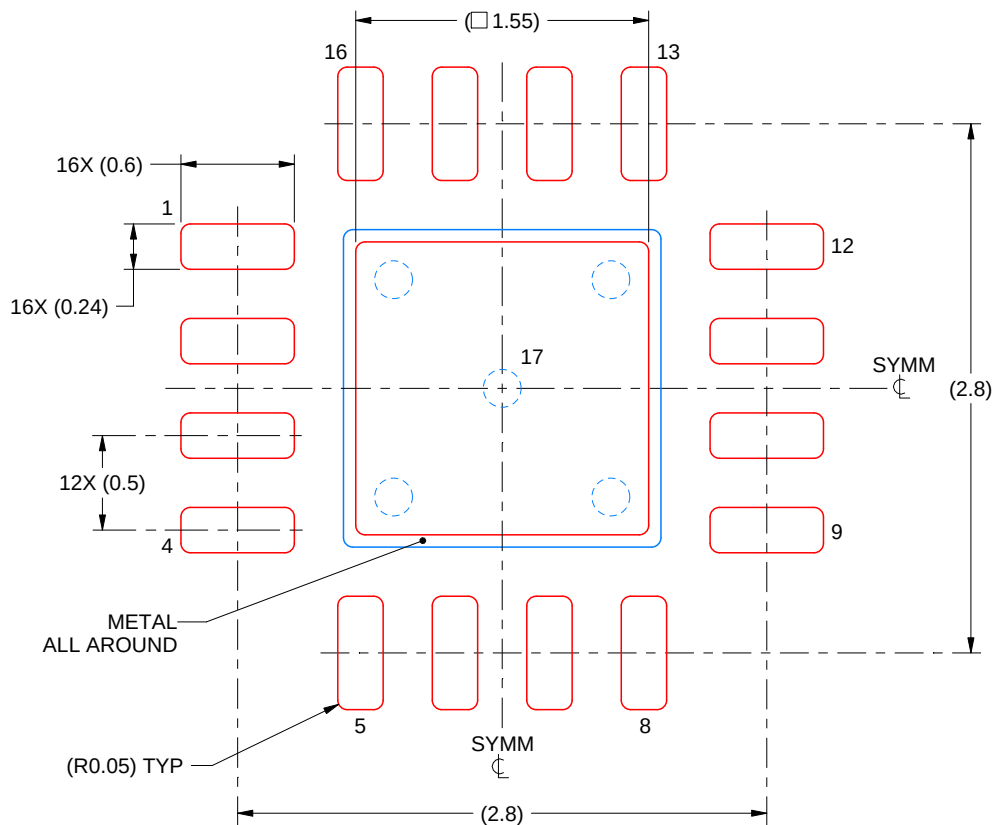
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RTE0016C

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 17:
85% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:25X

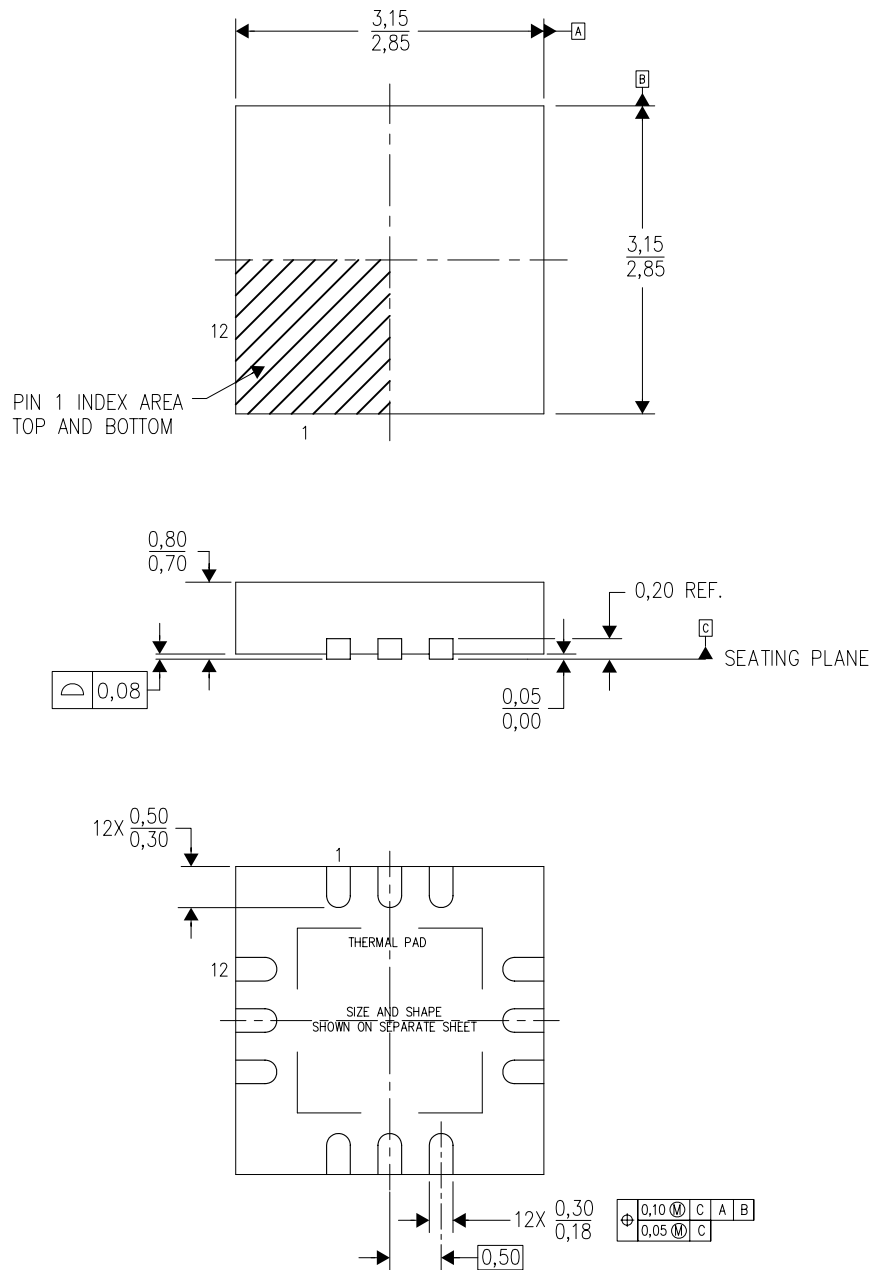
4219117/B 04/2022

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

RVK (S-PWQFN-N12)

PLASTIC QUAD FLATPACK NO-LEAD



4211889/B 10/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Quad Flatpack, No-leads (QFN) package configuration.
 - D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - F. Falls within JEDEC MO-220.

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